CORPORATION



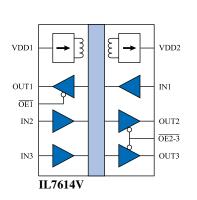
HY-LINE Power Components Vertriebs GmbH Inselkammerstr. 10 D-82008 Unterhaching © +49 89/ 614 503 -10 power@hy-line.de

HY-LINE AG CH-8200 Schaffhausen © +41 52 647 42 00 info@hy-line.ch

IL76xx

## High-Speed Data Couplers with Integrated DC-DC Convertors

#### **Block Diagrams** VDD1 VDD2 VDD1 VDD2 OUT1 IN1 IN1 OUT1 OUT2 OUT2 IN2



IL7611V

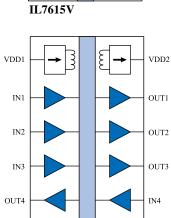
VDD1

IN1

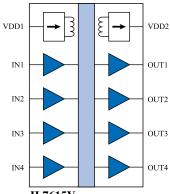
IN<sub>2</sub>

OUT3

IL7616V



IL7617V



IL7612V

## **Features**

- 110 Mbps
- Integrated 1/4 watt, 3.3-to-3.3 V DC-DC convertor
- Ultralow output ripple
- -40 °C to 125 °C temperature range
- Overcurrent and thermal shutdown protection
- Low EMI
- 4 kV<sub>RMS</sub> isolation
- VDE V 0884-11 certified and UL 1577 approved
- 0.3" True 8<sup>TM</sup> mm 16-pin SOIC package

## **Applications**

- Industrial automation
- IEC 60601 medical instrumentation
- Grid infrastructure
- Test and measurement
- Three-wire SPI
- Isolated ADCs and DACs

### Description

The IL76xx-Series are high-speed, fully-isolated, data couplers with integrated 3.3-to-3.3 V, one-quarter watt DC-DC convertors. This level of integration dramatically reduces chip count and board area.

The devices use NVE's proven, patented\* spintronic Giant Magnetoresistance (GMR) isolation technology and IsoLoop<sup>®</sup> high-efficiency micro-scale isolation transformers.

Frequency hopping and integrated shielding minimize EMI.

A unique ceramic/polymer composite barrier provides bestin-class isolation and virtually unlimited barrier life.

IsoLoop® is a registered trademark of NVE Corporation. \*U.S. Patent number 5,831,426; 6,300,617 and others.

VDD2

OUT1

OUT2

IN3



## Absolute Maximum Ratings(1)

Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Storage temperature	Ts	-55		150	°C	
Junction temperature	$T_{\rm J}$	-55		150	°C	
Supply voltage	$V_{ m DD1}$	-0.5		6	V	
Digital input voltage		-0.5		$V_{DD} + 0.5$	V	
Digital output voltage		-0.5		$V_{DD} + 1$	V	
Coupler output current drive	Io			10	mA	
Lead solder temperature				260	°C	10 sec.
ESD			2		kV	HBM

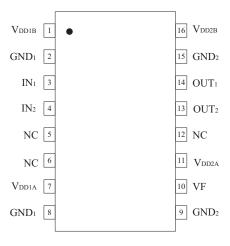
**Recommended Operating Conditions** 

teconimenate operating conditions								
Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions		
Input-side supply voltage	$V_{ ext{DD1}}$	3	3.3	3.6	V			
Isolated-side power supply input	$V_{\mathrm{DD2B}}$	2.7	3.3	5.5	V			
Ambient operating temperature	T <sub>min</sub> ; T <sub>max</sub>	-40		125	°C			
Junction temperature	$T_{\rm J}$	-40		150	°C			
High-level digital input voltage	$V_{\mathrm{IH}}$	2.4		$V_{ m DD1}$	V	$V_{DD1} = 3.3 \text{ V}$		
Low-level digital input voltage	$V_{IL}$	0		0.8	V			



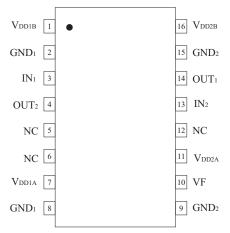
## **IL7611V Pin Connections**

1	$V_{\rm DD1B}$	Coupler controller-side power supply input (3.3 V nominal).
2	GND <sub>1</sub>	Ground return for $V_{DD1}$ (pins 2 and 8 internally connected).
3	$IN_1$	Data in, channel 1
4	$IN_2$	Data in, channel 2
5	NC	No internal connection
6	NC	No internal connection
7	V <sub>DD1A</sub>	DC-DC convertor input voltage (3.3 V nominal); bypass with 0.1 μF.
8	GND <sub>1</sub>	Ground return for V <sub>DD1</sub> (pins 2 and 8 internally connected).
9	GND <sub>2</sub>	Ground return for $V_{DD2}$ (pins 9 and 15 internally connected).
10	VF	Output-side rectifier output / regulator input; connect to a 0.1 µF/16 V external filter capacitor.
11	$V_{DD2A}$	Isolated DC-DC convertor output
12	NC	No internal connection
13	OUT <sub>2</sub>	Data out, channel 1
14	OUT <sub>1</sub>	Data out, channel 2
15	GND <sub>2</sub>	Ground return for $V_{DD2}$ (pins 9 and 15 internally connected).
16	$V_{\mathrm{DD2B}}$	Isolated-side power supply input (connect to pin 11 for normal operation)



## **IL7612V Pin Connections**

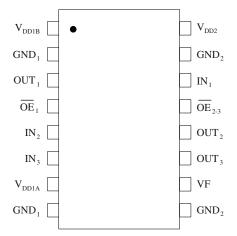
1	$V_{\rm DD1B}$	Coupler controller-side power supply input (3.3 V nominal).
2	GND <sub>1</sub>	Ground return for V <sub>DD1</sub> (pins 2 and 8 internally connected).
3	$IN_1$	Data in, channel 1
4	OUT <sub>2</sub>	Data out, channel 2
5	NC	No internal connection
6	NC	No internal connection
7	V <sub>DD1A</sub>	DC-DC convertor input voltage (3.3 V nominal); bypass with 0.1 µF.
8	GND <sub>1</sub>	Ground return for V <sub>DD1</sub> (pins 2 and 8 internally connected).
9	GND <sub>2</sub>	Ground return for $V_{DD2}$ (pins 9 and 15 internally connected).
10	VF	Output-side rectifier output / regulator input; connect to a 0.1 µF/16 V external filter capacitor.
11	$V_{DD2A}$	Isolated DC-DC convertor output
12	NC	No internal connection
13	$IN_2$	Data out, channel 1
14	OUT <sub>1</sub>	Data in, channel 2
15	GND <sub>2</sub>	Ground return for $V_{DD2}$ (pins 9 and 15 internally connected).
16	V <sub>DD2B</sub>	Isolated-side power supply input (connect to pin 11 for normal operation)





## **IL7614V Pin Connections**

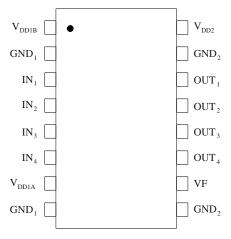
1	$V_{\rm DD1B}$	Coupler controller-side power supply input (3.3 V nominal).
2	GND <sub>1</sub>	Ground return for V <sub>DD1</sub> (pins 2 and 8 internally connected)
3	OUT <sub>1</sub>	Data out, channel 1
4	OE <sub>1</sub>	Channel 1 output enable (if high, $OUT_1$ = high impedance; has a 500 k $\Omega$ nominal internal pulldown)
5	IN <sub>2</sub>	Data in, channel 2
6	IN <sub>3</sub>	Data in, channel 3
7	<b>V</b>	DC-DC convertor input voltage (3.3 V nominal);
/	$V_{\rm DD1A}$	bypass with 0.1 μF.
8	GND <sub>1</sub>	Ground return for V <sub>DD1</sub> (pins 2 and 8 internally connected)
9	$GND_2$	Ground return for V <sub>DD2</sub> (pins 9 and 15 internally connected)
10	VF	Output-side rectifier output / regulator input;
10	٧r	connect to a 0.1 µF/16 V external filter capacitor.
11	OUT <sub>3</sub>	Data out, channel 3
12	OUT <sub>2</sub>	Data out, channel 2
13	OE <sub>2-3</sub>	Channel 2 and 3 output enable (if high, OUT <sub>2</sub> and OUT <sub>3</sub> are high
1.3	OL2-3	impedance; has a 500 kΩ nominal internal pulldown)
14	$IN_1$	Data in, channel 1
15	GND <sub>2</sub>	Ground return for V <sub>DD2</sub> (pins 9 and 15 internally connected)
16	$V_{\mathrm{DD2}}$	Isolated supply voltage





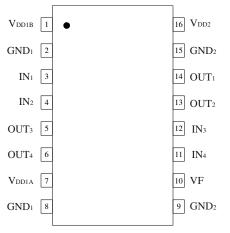
## **IL7615V Pin Connections**

1	$V_{\rm DD1B}$	Coupler controller-side power supply input (3.3 V nominal).
2	GND <sub>1</sub>	Ground return for V <sub>DD1</sub> (pins 2 and 8 internally connected).
3	$IN_1$	Data in, channel 1
4	$IN_2$	Data in, channel 2
5	IN <sub>3</sub>	Data in, channel 3
6	IN <sub>4</sub>	Data in, channel 4
7	17	DC-DC convertor input voltage (3.3 V nominal);
/	$V_{\rm DD1A}$	bypass with 0.1 μF.
8	GND <sub>1</sub>	Ground return for V <sub>DD1</sub> (pins 2 and 8 internally connected).
9	GND <sub>2</sub>	Ground return for V <sub>DD2</sub> (pins 9 and 15 internally connected).
10	VF	Output-side rectifier output / regulator input; connect to a
10	٧r	0.1 μF/16 V external filter capacitor.
11	OUT <sub>4</sub>	Data out, channel 4
12	OUT <sub>3</sub>	Data out, channel 3
13	OUT <sub>2</sub>	Data out, channel 2
14	OUT <sub>1</sub>	Data out, channel 1
15	GND <sub>2</sub>	Ground return for $V_{DD2}$ (pins 9 and 15 internally connected).
16	$V_{\mathrm{DD2}}$	Isolated supply voltage



## **IL7616V Pin Connections**

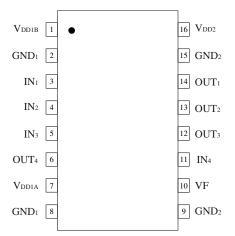
1	$V_{\rm DD1B}$	Coupler controller-side power supply input (3.3 V nominal).
2	GND <sub>1</sub>	Ground return for V <sub>DD1</sub> (pins 2 and 8 internally connected).
3	$IN_1$	Data in, channel 1
4	$IN_2$	Data in, channel 2
5	OUT <sub>3</sub>	Data out, channel 4
6	OUT4	Data out, channel 4
7	17	DC-DC convertor input voltage (3.3 V nominal);
/	$V_{\rm DD1A}$	bypass with 0.1 μF.
8	GND <sub>1</sub>	Ground return for $V_{DD1}$ (pins 2 and 8 internally connected).
9	GND <sub>2</sub>	Ground return for V <sub>DD2</sub> (pins 9 and 15 internally connected).
10	VF	Output-side rectifier output / regulator input; connect to a
10	٧r	0.1 μF/16 V external filter capacitor.
11	IN <sub>4</sub>	Data in, channel 4
12	IN <sub>3</sub>	Data in, channel 3
13	OUT <sub>2</sub>	Data out, channel 2
14	OUT <sub>1</sub>	Data out, channel 1
15	GND <sub>2</sub>	Ground return for $V_{DD2}$ (pins 9 and 15 internally connected).
16	$V_{\mathrm{DD2}}$	Isolated supply voltage





## **IL7617V Pin Connections**

1	$V_{\rm DD1B}$	Coupler controller-side power supply input (3.3 V nominal).
2	GND <sub>1</sub>	Ground return for V <sub>DD1</sub> (pins 2 and 8 internally connected).
3	$IN_1$	Data in, channel 1
4	$IN_2$	Data in, channel 2
5	IN <sub>3</sub>	Data in, channel 3
6	OUT <sub>4</sub>	Data out, channel 4
7	$V_{DD1A}$	DC-DC convertor input voltage (3.3 V nominal); bypass with 0.1 µF.
8	GND <sub>1</sub>	Ground return for V <sub>DD1</sub> (pins 2 and 8 internally connected).
9	GND <sub>2</sub>	Ground return for V <sub>DD2</sub> (pins 9 and 15 internally connected).
10	VF	Output-side rectifier output / regulator input; connect to a 0.1 µF/16 V external filter capacitor.
11	IN <sub>4</sub>	Data in, channel 4
12	OUT <sub>3</sub>	Data out, channel 3
13	OUT <sub>2</sub>	Data out, channel 2
14	OUT <sub>1</sub>	Data out, channel 1
15	GND <sub>2</sub>	Ground return for V <sub>DD2</sub> (pins 9 and 15 internally connected).
16	$V_{\mathrm{DD2}}$	Isolated supply voltage





## $\textbf{Coupler Specifications} \; (V_{\text{DD}} = 3.3 \; V; \; T_{\text{min}} \; \text{to} \; T_{\text{max}} \; \text{unless otherwise stated})$

Electrical Specifications								
Parameters	Symbol	Min.	Тур.	Max.	Units	Test Conditions		
Controller-side coupler quiescent su	pply current	•						
IL7611V			0.01	0.015				
IL7612V			1.2	1.75				
IL7614V	T		1.2	1.75	A			
IL7615V	$I_{DD1B}$		0.3	0.4	mA			
IL7616V			2.4	3.5				
IL7617V			1.2	1.75				
Isolated-side quiescent supply curre	nt							
IL7611V			2.4	3.5				
IL7612V			1.2	1.75				
IL7614V	т		2.4	3.5	4			
IL7615V	$I_{\mathrm{DD2}}$		4.8	7	mA			
IL7616V			2.4	3.5				
IL7617V			3.6	5.25				
Controller-side dynamic supply curre	ent	•						
IL7611V			0.3	0.5	mA/Mbps	All channels switching		
IL7612V			0.15	0.25				
IL7614V	T		0.3	0.5				
IL7615V	$I_{DD1B}$		0.6	1				
IL7616V			0.3	0.5				
IL7617V			0.45	0.75				
Isolated-side dynamic supply curren	it	•						
IL7611V			0.02	0.04				
IL7612V			0.15	0.25				
IL7614V			0.15	0.25		A11 1 1 1 1 1		
IL7615V	I <sub>DD2</sub>		0.02	0.04	mA/Mbps	All channels switching		
IL7616V			0.3	0.5	7			
IL7617V			0.15	0.25				
Logic input current	$I_{\rm I}$	-10		10	μA			
		$V_{DD} - 0.1$	$V_{ m DD}$			$I_0 = -20 \mu A, V_I = V_{IH}$		
Logic high output voltage	$V_{\mathrm{OH}}$	0.8 x V <sub>DD</sub>	0.9 x V <sub>DD</sub>		V	$I_0 = -4 \text{ mA}, V_I = V_{IH}$		
Logic low output voltage	V		0	0.1	V	$I_0 = 20 \mu A,  V_I = V_{IL}$		
Logic low output voltage	$V_{OL}$		0.5	0.8	7 v	$I_0 = 4 \text{ mA}, V_I = V_{IL}$		

Coupler Switching Specifications								
Maximum data rate		100	110		Mbps	$C_L = 15 \text{ pF}$		
Pulse width <sup>(6)</sup>	PW	10			ns	50% Points, Vo		
Propagation delay input to output (high to low)	t <sub>PHL</sub>		12	18	ns	$C_L = 15 \text{ pF}$		
Propagation delay input to output (low to high)	tplh		12	18	ns	$C_L = 15 \text{ pF}$		
Pulse width distortion <sup>(2)</sup>	PWD		2	3	ns	$C_L = 15 \text{ pF}$		
Propagation Delay difference between any two parts <sup>(3)</sup>	tpsk		4	6	ns	$C_L = 15 \text{ pF}$		
Output rise time (10%–90%)	$t_R$		2	4	ns	$C_L = 15 \text{ pF}$		
Output fall time (10%–90%)	$t_{\mathrm{F}}$		2	4	ns	$C_L = 15 \text{ pF}$		
Common mode transient immunity (output logic high or logic low) <sup>(4)</sup>	CM <sub>H</sub>  , CM <sub>L</sub>	30	50		kV/μs	$\begin{aligned} V_{\text{CM}} &= 1500 \ V_{\text{DC}} \\ t_{\text{TRANSIENT}} &= 25 \ \text{ns} \end{aligned}$		
Channel-to-channel skew	$t_{\rm CSK}$		2	3	ns	$C_L = 15 \text{ pF}$		

Coupler Magnetic Field Immunity <sup>(7)</sup>								
Power frequency magnetic immunity H <sub>PF</sub> 1000 1500 A/m 50Hz/60Hz								
Pulse magnetic field immunity	$H_{PM}$	1800	2000		A/m	$t_p = 8\mu s$		
Damped oscillatory magnetic field	Hosc	1800	2000		A/m	0.1Hz – 1MHz		
Cross-axis immunity multiplier <sup>(8)</sup>	Kx		2.5					



DC-DC Convertor Specifications

	T <sub>min</sub> to T <sub>max</sub> and V <sub>D</sub>	$D_1 = 3.0 \text{ V to}$	3.6 V unless of	herwise stated	l	
Parameter	Symbol	Min.	Тур.	Max.	Units	<b>Test Conditions</b>
Output voltage	$V_{\mathrm{DD2A}}$	2.7	3.3	3.45	V	$I_{DD2A}$ < 80 mA
Output current (total available to internal transceiver and external load)	I <sub>DD2A</sub>	65			mA	
Overcurrent threshold	Т		150		A	Disable
Overcurrent inresnoid	${ m I}_{ m DD2A}$		145		mA	Re-enable
Short-circuit protection limited current		115	125	135	mA	
Controller-side quiescent supply current	$I_{DD1AQ}$		200	240	mA	No external load on VDD2
Controller-side supply current	$I_{DD1A}$		380	440	mA	Maximum DC-DC convertor load
Line regulation	$\Delta V_{DD2}/\Delta V_{DD1A}$		32 16	40	mV/V	25 °C 125 °C
Load regulation	$\Delta V_{DD2}/V_{DD2}$		5	6	%	$I_{DD2} = 0$ to max.
Output voltage temperature coefficient	$(\Delta V_{DD2}/V_{DD2})/\Delta T$		0.017 0.03		%/C	$I_{DD2} = 10 \text{ mA}$ $I_{DD2} = 50 \text{ mA}$
Capacitive load	$C_{\mathrm{DD2}}$			1000	μF	
Output valtage ripple	Vana nyany s			5	mV <sub>P-P</sub>	20 MHz bandwidth; $I_{DD2} = max$ .
Output voltage ripple	VDD2-RIPPLE		1		III V P-P	1 kHz bandwidth; $I_{DD2} = max$ .
Start-up current	I <sub>DD1-SU</sub>		600	750	mA	700 ns max.
St. t. t.	,		200			No load
Start-up time	tsu		400		μs	Full load (resistive)
Convertor frequency	fosc	105	113	120	MHz	



**Isolation Specifications** 

Parameter	Symbol	Min.	Тур.	Max.	Units	<b>Test Conditions</b>
Isolation voltage*	$V_{\rm ISO}$	5000			$V_{RMS}$	
Transient overvoltage	$V_{\text{IOTM}}$	6000			$V_{PK}$	Per VDE V 0884-11
Surge immunity		12800			$V_{PK}$	
Creepage distance (external)		8.03	8.3		mm	Per IEC 60601
Total barrier thickness (internal)		0.012	0.016		mm	
Barrier resistance	$R_{IO}$		>1014		Ω	$500 \text{ V}_{\text{RMS}}$
Barrier capacitance	C <sub>IO</sub>		7		pF	f = 1  MHz
Leakage current			0.2		$\mu A_{RMS}$	240 V <sub>RMS</sub> , 60 Hz
Comparative tracking index	CTI	≥600			$V_{RMS}$	Per IEC 60112
Barrier life			44000	000	Years	100°C, 1000 V <sub>RMS</sub> , 60%
						CL activation energy

<sup>\*</sup> VDE V 0884-11 Basic Isolation certified under VDE File Number 5016933-4880-0001.

Parts 100% tested at 4.8 kV<sub>RMS</sub> (6.79 kV<sub>PK</sub>) for 1 second, 5 pC partial discharge limit under the stringent IEC60747-17 standard. Each lot sample tested at 4 kV<sub>RMS</sub> (5.66 kV<sub>PK</sub>) for 1 minute.

#### **Thermal Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Units	<b>Test Conditions</b>
Junction–ambient thermal resistance	$\theta_{ m JA}$		67		°C/W	Double-sided PCB with thermal vias in free air
Junction–case (top) thermal resistance	$\theta_{ m JC}$		12			
Junction–ambient thermal resistance	$\theta_{ m JA}$		46			2s2p PCB with thermal vias per JESD51 with thermal vias in free air
Junction–case (top) thermal resistance	$\theta_{ m JC}$		9			
Power dissipation	$P_{D}$			1.6	W	

#### Notes:

- Absolute Maximum specifications mean the device will not be damaged if operated under these conditions. It does not guarantee performance.
- 2. PWD is defined as lt<sub>PHL</sub> - t<sub>PLH</sub>l. %PWD is equal to PWD divided by pulse width.
- 3. t<sub>PSK</sub> is the magnitude of the worst-case difference in t<sub>PHL</sub> and/or t<sub>PLH</sub> between devices at 25°C.
- $CM_H$  is the maximum common mode voltage slew rate that can be sustained while maintaining  $V_0 > 0.8 \ V_{DD2}$ .  $CM_L$  is the maximum common mode input voltage that can be sustained while maintaining  $V_0 < 0.8$  V. The common mode voltage slew rates apply to both rising and falling common mode voltage edges.
- Device is considered a two terminal device: pins 1–8 shorted and pins 9–16 shorted. 5.
- 6. Minimum pulse width is the minimum value at which specified PWD is guaranteed.
- 7. The relevant test and measurement methods are given in the Electromagnetic Compatibility section.
- 8. External magnetic field immunity is improved by this factor if the field direction is "end-to-end" rather than to "pin-to-pin" (see diagram in the Electromagnetic Compatibility section).

UL 1577 approved under Component Recognition Program File Number E207481.



#### **Device Operation**

## **DC-DC Convertor Operation**

The DC-DC convertor block diagram is shown in Figure 1:

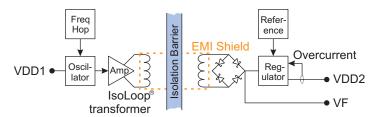


Figure 1. DC-DC convertor block diagram.

A 113 MHz oscillator drives a high-frequency power amplifier, which in turn drives an IsoLoop<sup>®</sup> microtransformer primary. Frequency hopping reduces EMI peak amplitudes, and embedded magnetic shielding further reduces radiated EMI.

A unique ceramic/polymer composite barrier provides best-in-class 5 kV isolation with virtually unlimited barrier life.

On the other side of the isolation barrier, the transformer secondary output is filtered, rectified, and regulated by a low-EMI low drop-out regulator with a precision bandgap voltage reference.

## Simple Capacitive Decoupling

The only external parts required are a 0.1  $\mu$ F capacitor placed as close as possible to the  $V_{DD1B}$  supply pin, a 10  $\mu$ F ceramic capacitor for the  $V_{DD2}$  pin, and a 0.1  $\mu$ F/16 V filter capacitor near the  $V_F$  pin. This low external parts count reduces board area and cost.

#### Start-Up Current

The input power supply to the DC-DC convertor must be able to supply a start-up surge current of 750 mA for at least 700 ns for the DC-DC convertor to start up properly. If the input current is supplied by a regulator, a one-amp regulator provides adequate current.

#### Short-Circuit Protection

The output current is internally limited to approximately 125 mA. This provides short-circuit protection and eliminates the need for external protection circuitry.

#### **GMR Isolator Operation**

An equivalent circuit for each of the Giant Magnetoresistor (GMR) isolator channels is shown in Figure 2:

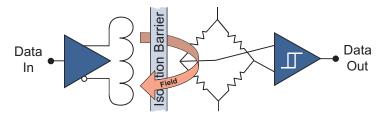


Figure 2. Isolator model signal path.

The GMR isolator signal path starts with a buffered input signal that is driven through an ultraminiature coil. This generates a small magnetic field that changes the electron spin polarization of GMR resistors, which are configured as a Wheatstone bridge. The change in spin polarization of the resistors creates a bridge voltage which drives an output comparator to construct an isolated version of the input signal. GMR is inherently high speed and low distortion.

#### **Dynamic Power Consumption**

NVE Isolators achieve their low power consumption from the way they transmit data across the isolation barrier. By detecting the edge transitions of the input logic signal and converting these to narrow current pulses, a magnetic field is created around the GMR Wheatstone bridge. Depending on the direction of the magnetic field, the bridge causes the output comparator to switch following the input logic signal. Since the current pulses are narrow, about 2.5 ns, the power consumption is independent of mark-to-space



ratio and solely dependent on frequency. This has obvious advantages over optocouplers, which have power consumption heavily dependent on mark-to-space ratio.

Power consumption increases with frequency for the input side of each channel, but output-side power consumption is constant for a particular isolator channel. For channels with inputs on the  $V_{DD2}$  side, the dynamic power consumption must be provided by the DC-DC convertor, so  $V_{DD1B}$  supply current increases with the frequency of that channel.

#### Current Drawn From the Output of the DC-DC Convertor by the Coupler Section

The current drawn from the output of the DC-DC convertor by the coupler section consists of the coupler's isolated-side quiescent current, plus, in the case of the IL7614V, isolated-side dynamic current. So, for example, for an IL7614V, the isolated-side quiescent current is 3.5 mA, the dynamic current is 0.24 mA/Mbps, so if the coupler is running at 100 Mbps, the dynamic current is 24 mA and the total current is 27.5 mA. Since the DC-DC convertor can supply up to 80 mA, the IL7614 can therefore supply up to 52.5 mA to external loads. Of course the DC-DC convertor can supply more if the coupler channels are running below full speed.

## **Optional External Regulation**

An external regulator can be used in place of the parts' internal low drop-out regulator for voltages up to approximately 8 volts. The maximum output current decreases at higher regulator output voltages, but the output power capacity remains approximately 250 milliwatts.

#### **Maintaining Creepage**

Creepage distances are often critical in isolated circuits. In addition to meeting JEDEC standards, NVE isolator packages have unique creepage specifications. Standard pad libraries often extend under the package, compromising creepage and clearance. Similarly, ground planes, if used, should be spaced to avoid compromising clearance. Package drawings and recommended pad layouts are included in this datasheet.

#### Coupler Status on Start-up and Shut Down

To minimize power dissipation, coupler input signals are differentiated and then latched on the output side of the isolation barrier to reconstruct the signal. This could result in an ambiguous output state depending on power up, shutdown and power loss sequencing. Therefore, the designer should consider including an initialization signal in the start-up circuit. Initialization consists of toggling the input either high then low, or low then high.

#### **Power and Thermal Management**

Note that self-heating generated by the quiescent current of the DC-to-DC convertor generally limits the ambient operating temperature to less than 125 °C to avoid exceeding the 150 °C Absolute Maximum junction temperature. The isolator section will operate at 125 °C, however, if the DC-to-DC convertor is not used or is duty cycled.

The IL76xx typically operates well within the current limits of the DC-DC convertor unless the coupler is operating at high speed or there are external loads on the DC-DC convertor. Internal thermal management circuitry gradually limits the output voltage and power output as the junction temperature increases to avoid thermal overload. The coupler section is guaranteed to operate at the 2.7 volt minimum DC-DC convertor output voltage with 250 mW output power.

#### **Board Thermal Optimization**

Board layout can be optimized for thermal performance if necessary. A double sided, double buried power plane ("2s2p") board maximizes thermal performance. Thermal vias should be used between the power plane and the board surfaces. All of the IC ground pins should be connected, with wide traces to help cool the leadframe.

### **Maintaining Creepage**

Creepage distances are often critical in isolated circuits. In addition to meeting JEDEC standards, NVE isolator packages have unique creepage specifications. Standard pad libraries often extend under the package, compromising creepage and clearance. Similarly, ground planes, if used, should be spaced to avoid compromising clearance. Package drawings and recommended pad layouts are included in this datasheet.



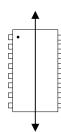
## **Inherently Low EMI**

IL76xx-Series parts designed for compliance with IEC 61000-6-3, IEC 61000-6-4, CISPR, and FCC Class A standards for emissions. The DC-DC convertor oscillator operates above 88 MHz, where emission limits are higher since there is less risk of interference with common commercial radio and television broadcasting.

Frequency-hopping technology dramatically reduces peak EMI, and synchronous rectification and PWM control are avoided, resulting in inherently low EMI. Ferrite beads are generally not required for EMI mitigation.

## **High Magnetic Immunity**

These parts are fully compliant with IEC 61000-6-1 and IEC 61000-6-2 magnetic immunity standards. The coupler's Wheatstone bridge configuration and differential magnetic field signaling ensure excellent EM immunity. Immunity to external magnetic fields is even higher if the field direction is "end-to-end" (rather than to "pin-to-pin") as shown at right.





## **Typical Performance Graphs**

The following graphs show typical performance:

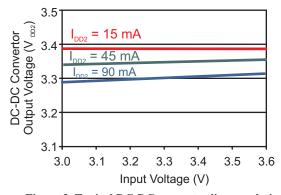


Figure 3. Typical DC-DC convertor line regulation.

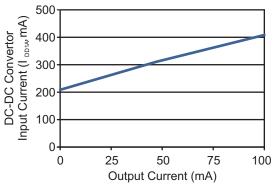


Figure 5. Typical DC-DC convertor supply current versus output current (V<sub>DD1</sub> = 3.3 V).

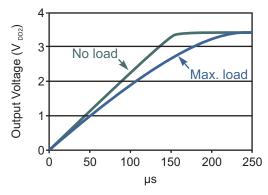


Figure 7. Typical DC-DC convertor startup.

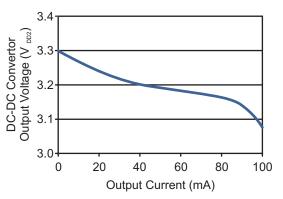


Figure 4. Typical DC-DC convertor load regulation ( $V_{\rm DD1}$  = 3.3 V).

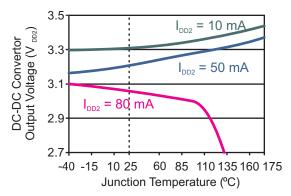


Figure 6. Typical DC-DC convertor output versus temperature ( $V_{DD1A}$  = 3.3 V).

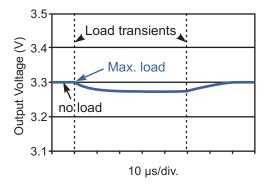


Figure 8. DC-DC convertor transient response.



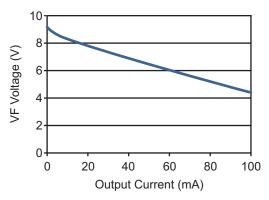


Figure 9. Typ. VF output vs. output current (V<sub>DD1A</sub> = 3.3 V; 25  $^{\circ}$ C).

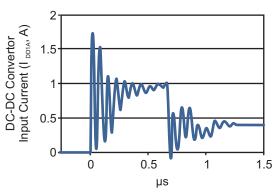


Figure 11. Typical start-up current (max. load; no V<sub>DD1</sub> bypass capacitor).

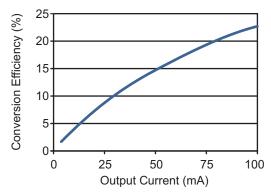


Figure 10. Typ. DC-DC convertor power efficiency  $(V_{DD1A} = 3.3 \text{ V}; 25 ^{\circ}\text{C}).$ 



## **Typical Applications**

#### **Isolated SPI interface to ADC:**

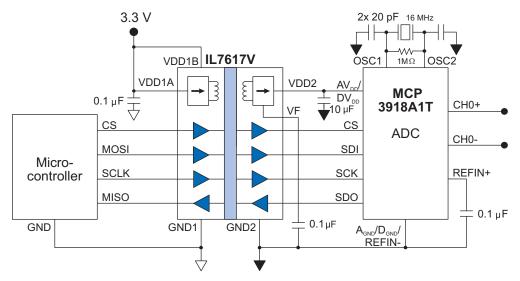


Figure 11. Isolated bidirectional SPI ADC interface.

The IL7617VE provides three transmit and one receive channel, making it ideal for isolating ubiquitous bidirectional SPI peripherals such as ADCs. The isolation allows safe connections to line voltage, and the isolated power supply prevents microcontroller noise from affecting the ADC.

#### **Isolated SPI sensor interface:**

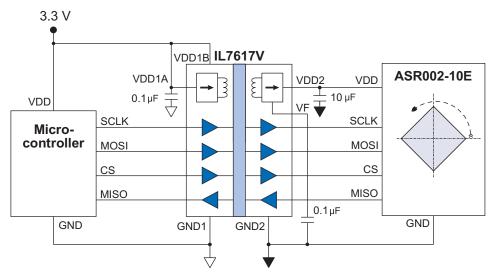


Figure 12. Isolated SPI sensor interface.

The IL7617VE provides three transmit and one receive channel, making it ideal for isolating classic SPI sensors. The isolated power supply prevents noise from the microcontroller from affecting the sensor.



## Isolated SPI / MICROWIRE interface to transmit-only ADC:

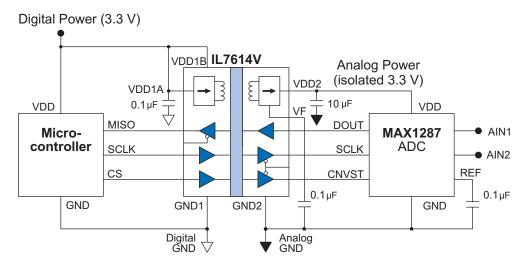


Figure 13. Isolated ADC serial interface.

Only three channels of isolation are required for transmit-only SPI peripherals such as ADCs or sensors. The IL7614VE provides an isolated analog power supply to significantly improve the noise performance of a successive-approximation ADC, and also isolates the serial interface.



#### Isolated shunt-based electric meter interface:

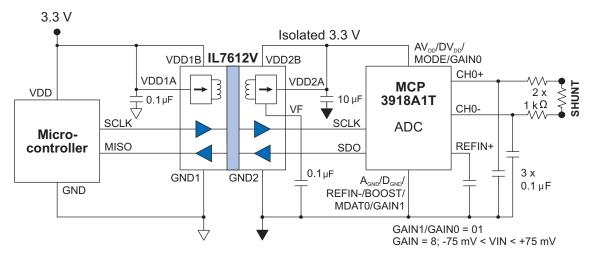


Figure 14. Isolated shunt-based current sensing.

Just two channels are needed to isolate unidirectional SPI-type interfaces that do not have chip-selects or other interface lines. The circuit above takes advantage of the "two-wire interface mode" of an MCP3918 ADC. The IL7612VE also supplies ADC power for shunt-based current sensing in the circuit above for power measurement systems such as electric meters. Unlike most optocouplers, the IL7612VE isolator section is fast enough for the ADC's 20 MHz high-speed SPI interface.

### Isolated SPI for receive-only DACs:

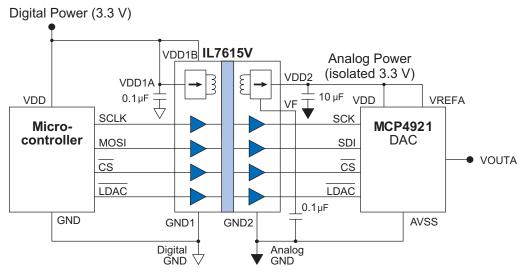


Figure 15. Isolated four-channel DAC interface.

The IL7615V provides four transmit channels of isolation for receive-only DACs with SPI plus additional lines. In the example above, the LDAC synchronization line is isolated, which transfers data from the serial interface latches to the output latches, as well as the SPI lines (SCLK, MOSI, and CS).



## Double-isolated parallel DAC interface:

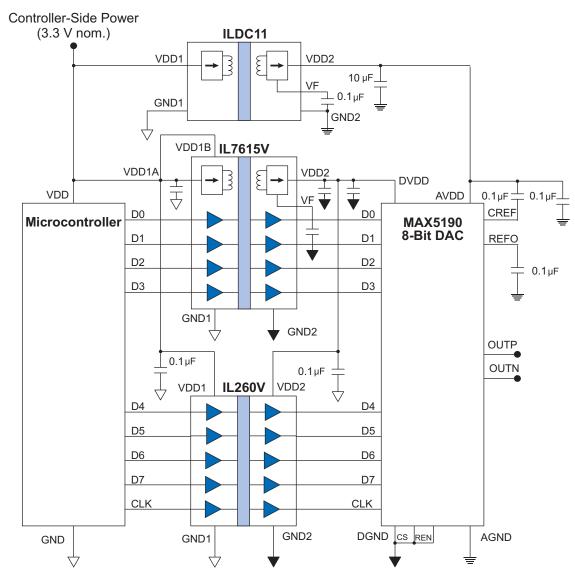
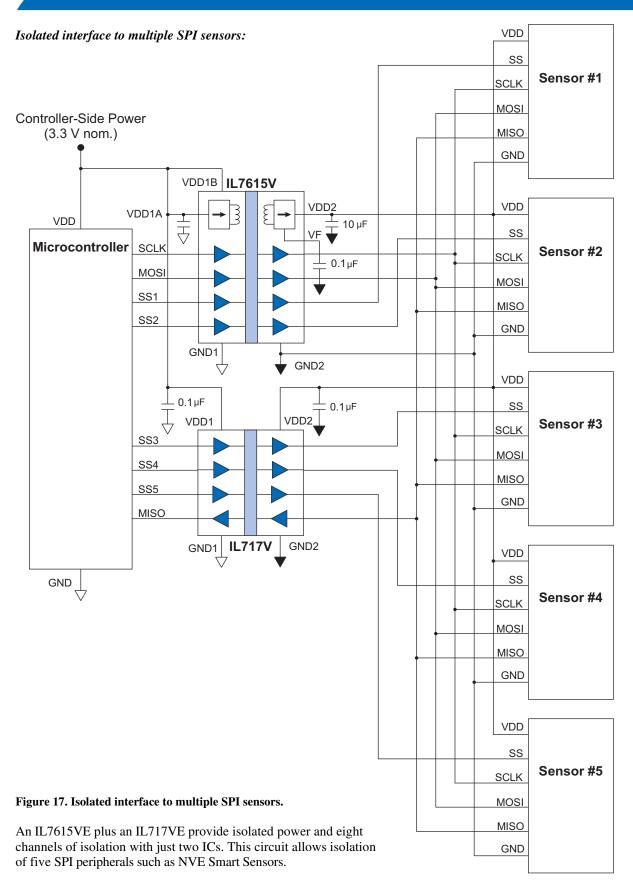


Figure 16. Double-isolated parallel DAC interface.

The IL7615V plus an IL260V provide isolated digital power and nine channels of isolation. This allows isolation of an eight-bit parallel peripheral such as a high-speed digital-to-analog convertor. The 110 Mbps speed of the IL7615V and IL260V couplers support the 40 MHz DAC used in this circuit. A separate ILDC11 DC-DC convertor provides an isolated analog power supply to improve noise performance by preventing digital noise from affecting the analog section of the DAC. The ILDC11's extremely low ripple also enhances the DAC's noise performance.







## 5-volt to 3.3-volt isolation:

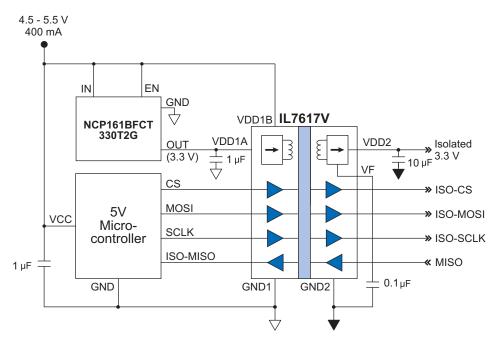
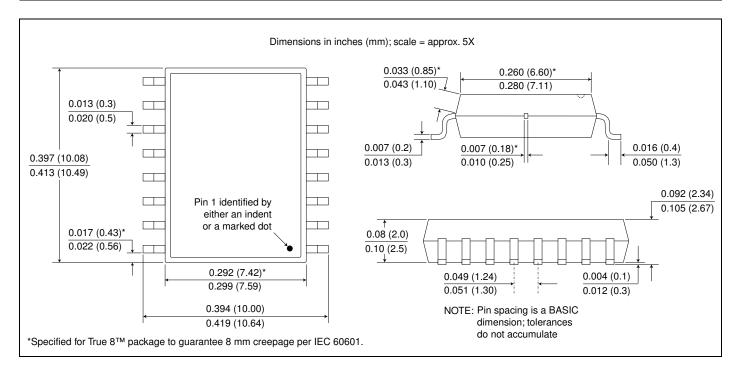


Figure 18. 5-volt to 3.3-volt isolation.

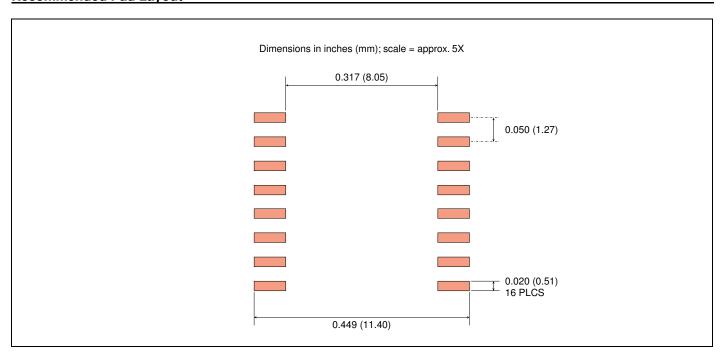
An inexpensive external regulator can be used to accommodate a 5-volt input to an IL76xxV's DC-DC convertor. For higher efficiency, a buck switching regulator such as a LM3691-3.3 can be used.



## **Package Drawing**



## **Recommended Pad Layout**





## **Available Part Numbers**

	Channels		
Part Number	(transmit/receive)	<b>Bulk Packaging</b>	RoHS?
IL7611VE	2/0	Duik I ackaging	KOIIS:
IL7612VE	1/1		
IL7614VE	2/1	Tubes	
IL7615VE	4/0	(50 pcs.)	
IL7616VE	2/2	(== 1)	
IL7617VE	3 / 1		
IL7611VE-TR7	2/0		
IL7612VE-TR7	1/1		RoHS
IL7614VE-TR7	2/1	7-inch reels	
IL7615VE-TR7	4/0	(up to 450 pcs.)	
IL7616VE-TR7	2/2		
IL7617VE-TR7	3 / 1		
IL7612VE-TR13	1/1		
IL7614VE-TR13	2/1		
IL7614VE-TR13	2/1	13-inch reels	
IL7615VE-TR13	4/0	(up to 1500 pcs.)	
IL7616VE-TR13	2/2		
IL7617VE-TR13	3 / 1		
IL7611V	2/0		
IL7612V	1 / 1		
IL7614V	2 / 1	Tubes	
IL7615V	4/0	(50 pcs.)	
IL7616V	2/2		
IL7617V	3 / 1		
IL7611V-TR7	2/0		SnPb finish (non-RoHS; Special Order)
IL7612V-TR7	1/1		
IL7614V-TR7	2/1	7-inch reels	
IL7615V-TR7	4/0	(up to 450 pcs.)	
IL7616V-TR7	2/2		
IL7617V-TR7	3/1		
IL7611V-TR13	2/0		
IL7612V-TR13	1/1	10	
IL7614V-TR13	2/1	13-inch reels	
IL7615V-TR13	4/0	(up to 1500 pcs.)	
IL7616V-TR13	2/2		
IL7617V-TR13	3 / 1		



## **Revision History**

# ISB-DS-001-IL76xx-Rev. B Sept. 2021

## Changes

- Corrected IL7616V (p. 5) and IL7617V (p. 6) pin-out diagrams.
- Changed isolation voltage to 4 kV under the more stringent IEC60747-17 standard.

# ISB-DS-001-IL76xx-Rev. A April 2021

## Changes

- Added IL7611V and IL7612V.
- Changed Absolute Maximum storage and junction temperatures to 150 °C.
- Added VF vs. output current typical performance graph.
- Added descriptions of external regulator options.
- Added IL7617V / ADC application circuit (Figure 11).
- Added IL7612V / ADC application circuit (Figure 14).
- Added IL7615V / DAC application circuit (Figure 15).

## ISB-DS-001-IL76xx-PRELIM3 August 2020

#### Changes

- Added thermal shutdown protection (p. 9) and graph (Figure 6).
- Added start-up current specification (p. 6) and typical graph (Figure 9).

## ISB-DS-001-IL76xx-PRELIM2 July 2020

## Change

• Added IL7616 and IL7617.

## ISB-DS-001-IL76xx-PRELIM July 2020

#### Change

Preliminary release.



#### **Datasheet Limitations**

The information and data provided in datasheets shall define the specification of the product as agreed between NVE and its customer, unless NVE and customer have explicitly agreed otherwise in writing. All specifications are based on NVE test protocols. In no event however, shall an agreement be valid in which the NVE product is deemed to offer functions and qualities beyond those described in the datasheet.

#### **Limited Warranty and Liability**

Information in this document is believed to be accurate and reliable. However, NVE does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NVE be liable for any indirect, incidental, punitive, special or consequential damages (including, without limitation, lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

#### Right to Make Changes

NVE reserves the right to make changes to information published in this document including, without limitation, specifications and product descriptions at any time and without notice. This document supersedes and replaces all information supplied prior to its publication.

#### **Use in Life-Critical or Safety-Critical Applications**

Unless NVE and a customer explicitly agree otherwise in writing, NVE products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical devices or equipment. NVE accepts no liability for inclusion or use of NVE products in such applications and such inclusion or use is at the customer's own risk. Should the customer use NVE products for such application whether authorized by NVE or not, the customer shall indemnify and hold NVE harmless against all claims and damages.

#### **Applications**

Applications described in this datasheet are illustrative only. NVE makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NVE products, and NVE accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NVE product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customers. Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NVE does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customers. The customer is responsible for all necessary testing for the customer's applications and products using NVE products in order to avoid a default of the applications and the products or of the application or use by customer's third party customers. NVE accepts no liability in this respect.

#### **Limiting Values**

Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the recommended operating conditions of the datasheet is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

#### **Terms and Conditions of Sale**

In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NVE hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NVE products by customer.

#### No Offer to Sell or License

Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

#### **Export Control**

This document as well as the items described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

#### **Automotive Qualified Products**

Unless the datasheet expressly states that a specific NVE product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NVE accepts no liability for inclusion or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NVE's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond NVE's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NVE for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NVE's standard warranty and NVE's product specifications.

Phone: (952) 829-9217





An ISO 9001 Certified Company

**NVE Corporation** 11409 Valley View Road Eden Prairie, MN 55344-3617 USA Telephone: (952) 829-9217

www.nve.com

e-mail: iso-info@nve.com



HY-LINE Power Components Vertriebs GmbH Inselkammerstr. 10 D-82008 Unterhaching © +49 89/ 614 503 -10 power@hy-line.de

HY-LINE AG Hochstrasse 355 CH-8200 Schaffhausen © +41 52 647 42 00 info@hy-line.ch

©NVE Corporation

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

ISB-DS-001-IL76xx-Rev. B

Sept. 2021